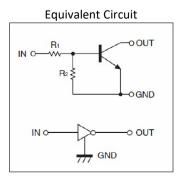


FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy



PIN CONNENCTIONS and MARKING



ORDERING INFORMATION

Part Number	MARKING	Package	Packing Method	Pack Quantity
DTC114ECA	24	SOT-23	Reel	3000pcs/Reel

MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

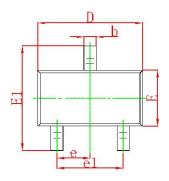
Symbol	Parameter	Limits	Unit
Vcc	Supply Voltage	200	V
Vin	Input Voltage	-10∼+12	V
lo	Output Current	100	mA
PD	Power Dissipation	200	mW
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55∼+150	°C

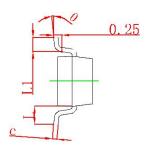
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

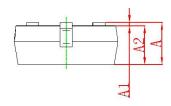
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =5V,I _O =100μA	0.5			٧
	V _{I(on)}	V _O =0.3V,I _O =20mA			3	٧
Output voltage	V _{O(on)}	I _O /I _I =10mA/0.5mA			0.3	٧
Input current	I _I	V _I =5V			3.8	mA
Output current	I _{O(off)}	V _{CC} =50V,V _I =0			0.5	μA
DC current gain	Gı	V ₀ =5V,I ₀ =20mA	20			
Input resistance	R ₁		1.54	2.2	2.86	kΩ
Resistance ratio	R ₂ /R ₁		0.8	1	1.2	
Transition frequency	f _T	V _O =10V,I _O =5mA,f=100MHz		250		MHz



SOT-23 Package information







Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
С	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
е	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout

